







SN54AHC125, SN74AHC125

## SCLS256M - DECEMBER 1995 - REVISED JUNE 2023

## **SNx4AHC125 Quadruple Bus Buffer Gates With 3-State Outputs**

#### 1 Features

- Operating Range: 2 V to 5.5 V
- Latch-Up Performance Exceeds 250 mA Per JESD
- Four Individual Output Enable Pins

## 2 Applications

- Flow Meters
- **Programmable Logic Controllers**
- Power Over Ethernet (PoE)
- Motor Drives and Controls
- Electronic Point-of-Sale

## 3 Description

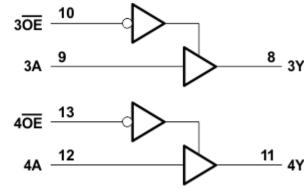
The SNx4AHC125 devices are quadruple bus buffer gates featuring independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ( $\overline{OE}$ ) input is high. When  $\overline{OE}$  is low, the respective gate passes the data from the A input to its Y output.

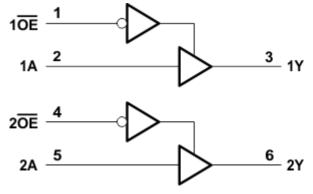
To ensure the high-impedance state during power up or power down,  $\overline{OE}$  must be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM) 2		
	J (CDIP, 14)	8.89 mm 8.89 mm		
SN54AHC125	W (CFP, 14)	19.56 mm × 6.67 mm		
	FK (LCCC, 20)	9.21 mm × 5.97 mm		
	DB (SSOP, 14)	6.20 mm 5.30 mm		
	D (SOIC, 14)	8.65 mm × 3.91 mm		
	NS (SO, 14)	10.30 mm × 5.30 mm		
SN74AHC125	DGV (TVSOP, 14)	3.60 mm × 4.40 mm		
3N/4AIIC123	PW (TSSOP, 14)	5.00 mm × 4.40 mm		
	N (PDIP, 14)	19.30 mm × 6.35 mm		
	RGY (VQFN, 14)	3.50 mm × 3.50 mm		
	BQA (WQFN, 14)	3 mm × 2.5 mm		

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.





Pin numbers shown are for the D, DB, DGV, J, N, NS, PW, RGY, and W packages.

Logic Diagram (Positive Logic)



## **Table of Contents**

1 Features	12
2 Applications	
3 Description	
4 Revision History	
5 Pin Configuration and Functions	13
<b>6 Specifications</b> 9.1 Application Information	
6.1 Absolute Maximum Ratings	
6.2 ESD Ratings	
6.3 Recommended Operating Conditions	
6.4 Thermal Information	16
6.5 Electrical Characteristics	16
6.6 Switching Characteristics, V <sub>CC</sub> = 3.3 V ± 0.3 V8 10.2 Receiving Notification of Documentation	
6.7 Switching Characteristics, V <sub>CC</sub> = 5 V ± 0.5 V9 10.3 Support Resources	16
6.8 Noise Characteristics	
6.9 Operating Characteristics	16
6.10 Typical Characteristics	16
7 Parameter Measurement Information	
8 Detailed Description	16

## **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision L (November 2016) to Revision M (June 2023)	Page
•	Added BQA package to Package Information table	1
•	Updated RθJA values: D = 92.6 to 124.5, PW = 121.5 to 147.7, all values in °C/W	6
•	Added thermal value for RθJA: BQA = 88.3, all values in °C/W	6
C	hanges from Revision K (June 2013) to Revision L (November 2016)	Page
•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section  Deleted Ordering Information table; see Package Option Addendum at the end of the data sheet	
•	Changed Package thermal impedance, R <sub>0,JA</sub> , value in <i>Thermal Information</i> table From: 86°C/W To: 92°C/W To: 107.3°C/W (DB), From: 127°C/W To: 134.6°C/W (DGV), From: 80°C/W To: 56°C/W To: 76°C/W To: 89.9°C/W (NS), and From: 113°C/W To: 121.5°C/W (PW)	2.6°C/W 5.3°C/W



## **5 Pin Configuration and Functions**

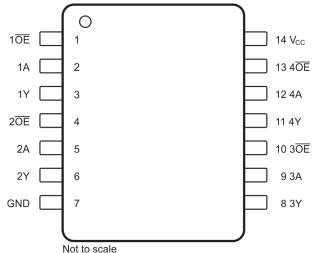


Figure 5-1. D, DB, DGV, N, NS, J, W, or PW Package 14-Pin SOIC, SSOP, TVSOP, PDIP, SO, CDIP, CFP, or TSSOP Top View

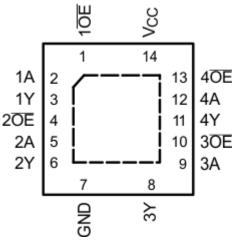


Figure 5-2. RGY or BQA Package 14-Pin VQFN Top View

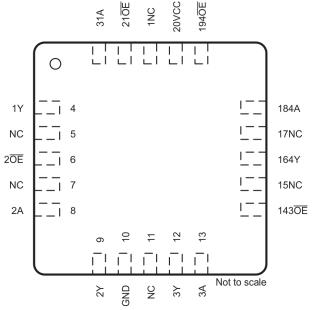


Figure 5-3. FK Package 20-Pin LCCC Top View



## **Table 5-1. Pin Functions**

	PIN	142		
NAME	SOIC, SSOP, TVSOP, PDIP, SO, CDIP, CFP, TSSOP, VQFN	LCCC	I/O	DESCRIPTION
1 ŌE	1	2	I	Output enable for gate 1
1A	2	3	I	Gate 1 input
1Y	3	4	0	Gate 1 output
2 OE	4	6	ı	Output enable for gate 2
2A	5	8	I	Gate 2 input
2Y	6	9	0	Gate 2 output
3 OE	10	14	I	Output enable for gate 3
3A	9	13	ı	Gate 3 input
3Y	8	12	0	Gate 3 output
4 OE	13	19	I	Output enable for gate 4
4A	12	18	I	Gate 4 input
4Y	11	16	0	Gate 4 output
GND	7	10	_	Ground pin
NC	_	1, 5, 7, 11, 15, 17	_	No internal connection
V <sub>CC</sub>	14	20	_	Power pin



## 6 Specifications

## **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

	,	MIN	MAX	UNIT	
but voltage <sup>(2)</sup> It clamp current $V_1 < 0$ But clamp current $V_0 < 0 \text{ or } V_0 > V_{CC}$ It tinuous output current $V_0 = 0 \text{ to } V_{CC}$ It tinuous current through $V_{CC}$ or GND		-0.5	7	V	
Input voltage <sup>(2)</sup>		-0.5	7	V	
Output voltage <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V	
Input clamp current	V <sub>1</sub> < 0		-20	mA	
Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA	
Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>		±25	mA	
Continuous current through V <sub>CC</sub> or GND			±50	mA	
Virtual operating junction temperature, T <sub>J</sub>	t clamp current $V_{I} < 0$ but clamp current $V_{O} < 0 \text{ or } V_{O} > V_{CC}$ tinuous output current $V_{O} = 0 \text{ to } V_{CC}$ tinuous current through $V_{CC}$ or GND				
Storage temperature, T <sub>stg</sub>	$\begin{array}{cccccccccccccccccccccccccccccccccccc$				

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

			VALUE	UNIT
V		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±1500	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

## **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage		2	5.5	V	
		V <sub>CC</sub> = 2 V	1.5			
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 3V	2.1		V	
		V <sub>CC</sub> = 5.5 V	3.85			
		V <sub>CC</sub> = 2 V		0.5		
V <sub>IL</sub>	Low-level Input voltage	V <sub>CC</sub> = 3 V		0.9	V	
		V <sub>CC</sub> = 5.5 V		1.65		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 2 V		-50	μA	
I <sub>OH</sub>	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA	
		$V_{CC}$ = 5 V ±0.5 V		-8	ША	
		V <sub>CC</sub> = 2 V		50	μA	
I <sub>OL</sub>	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		
		V <sub>CC</sub> = 5 V ±0.5 V		8	mA	
Δt/Δν	Input Transition rice or fell rate	V <sub>CC</sub> = 3.3 V ±0.3 V		100	ns/V	
ΔΙ/Δ۷	Input Transition rise or fall rate  V <sub>CC</sub> = 5 V ±0.5 V			20	115/V	
T <sub>A</sub>	Operating free-air temperature		-40	125	°C	

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



#### **6.4 Thermal Information**

		SNx4AHC125								
	THERMAL METRIC(1)		DB (SSOP)	NS (SO)	DGV (TVSOP)	PW (TSSOP)	N (PDIP)	RGY (VQFN)	BQA (WQFN)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	124.5	107.3	89.9	134.6	147.7	56.3	55.1	88.3	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	52.7	59.3	47.7	53.9	50.2	43.9	52.3	90.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	46.8	54.7	48.6	63.8	63.2	36.1	30.9	56.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	19.7	24	17.5	6.3	6.1	29.2	2.4	9.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	46.6	54.1	48.3	63.2	62.7	36	31	56.7	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	_	_	_	_	_	_	12.7	33.4	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## 6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS				MAX	UNIT
			T <sub>A</sub> = 25°C	1.9	2		
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1.9			
		V <sub>CC</sub> = 2 V	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$	1.9			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1.9			
			T <sub>A</sub> = 25°C	2.9	3		
			$T_A = -55^{\circ}C \text{ to } 125^{\circ}C \text{ (SN54AHC125)}$	2.9			
	I <sub>OH</sub> = -50 μA	V <sub>CC</sub> = 3 V	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$	2.9			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	2.9			
		V <sub>CC</sub> = 4.5 V	T <sub>A</sub> = 25°C	4.4	4.5		
			$T_A = -55^{\circ}C$ to 125°C (SN54AHC125)	4.4			
V <sub>OH</sub>			$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$	4.4			V
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	4.4			
		ı	T <sub>A</sub> = 25°C	2.58			
			$T_A = -55^{\circ}C$ to 125°C (SN54AHC125)	2.48			
V <sub>ОН</sub>	$I_{OH}$ = -4 mA and $V_{CC}$ = 3 \	/	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$	2.48			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	2.48			
			T <sub>A</sub> = 25°C	3.94			
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	3.8			
	$I_{OH} = -8$ mA and $V_{CC} = 4.5$	5 V	T <sub>A</sub> = -40°C to 85°C (SN74AHC125)	3.8			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	3.8			



## **6.5 Electrical Characteristics (continued)**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONI	DITIONS	MIN T	YP MAX	UNIT		
			T <sub>A</sub> = 25°C		0.1			
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)		0.1			
		V <sub>CC</sub> = 2 V	$T_A = -40^{\circ}\text{C to }85^{\circ}\text{C (SN74AHC125)}$		0.1			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		0.1			
			T <sub>A</sub> = 25°C		0.1			
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)		0.1			
	I <sub>OL</sub> = 50 μA	V <sub>CC</sub> = 3 V	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$		0.1			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		0.1			
			T <sub>A</sub> = 25°C		0.1			
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)		0.1			
$V_{OL}$		V <sub>CC</sub> = 4.5 V	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$		0.1	V		
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		0.1			
		-	T <sub>A</sub> = 25°C		0.36			
			$T_A = -55^{\circ}C$ to 125°C (SN54AHC125)		0.5			
	$I_{OH}$ = 4 mA and $V_{CC}$ = 3 V		$T_A = -40$ °C to 85°C (SN74AHC125)		0.44			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		0.5			
			T <sub>A</sub> = 25°C		0.36			
			$T_A = -55^{\circ}C \text{ to } 125^{\circ}C \text{ (SN54AHC125)}$		0.5			
	$I_{OH}$ = 8 mA and $V_{CC}$ = 4.5 V		$T_A = -40^{\circ}\text{C to }85^{\circ}\text{C (SN74AHC125)}$		0.44			
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		0.5			
			T <sub>A</sub> = 25°C		±0.1			
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)		±1 <sup>(1)</sup>			
l <sub>l</sub>	$V_I = 5.5 \text{ V or GND an}$	$d V_{CC} = 0 V to 5.5 V$	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$		±1	μΑ		
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		±1			
			T <sub>A</sub> = 25°C		±0.25			
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)		±2.5			
l <sub>oz</sub>	$V_O = V_{CC}$ or GND and	$dV_{CC} = 5.5 V$	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$		±2.5	μΑ		
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		±2.5			
			T <sub>A</sub> = 25°C		4			
			T <sub>A</sub> = -55°C to 125°C (SN54AHC125)		40			
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O =$	= 0, and $V_{CC}$ = 5.5 V	T <sub>A</sub> = -40°C to 85°C (SN74AHC125)		40	μΑ		
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)		40			
0	V = V == CND	\/ - F \/	T <sub>A</sub> = 25°C	,	4 10	"r		
Ci	$V_I = V_{CC}$ or GND and	$V_{CC} = 5 V$	T <sub>A</sub> = -40°C to 85°C (SN74AHC125)		10	pF		

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested at  $V_{CC} = 0 \text{ V}$ .



## 6.6 Switching Characteristics, $V_{CC}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range and  $V_{CC}$  = 3.3 V  $\pm$  0.3 V (unless otherwise noted; see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		TEST CONDITIONS	MIN	TYP	MAX	UNIT						
				T <sub>A</sub> = 25°C		5.6 <sup>(1)</sup>	8 <sup>(1)</sup>							
	۸	Y	C <sub>L</sub> = 15 pF	T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1(1)		9.5 <sup>(1)</sup>	ns						
t <sub>PHL</sub> , t <sub>PLH</sub>	Α	Ţ	CL - 15 PF	$T_A = -40$ °C to 85°C (SN74AHC125)	1		9.5	] 115						
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		9.5							
				T <sub>A</sub> = 25°C		5.4 <sup>(1)</sup>	8 <sup>(1)</sup>							
	ŌĒ	Y	C <sub>L</sub> = 15 pF	T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1(1)		9.5 <sup>(1)</sup>							
t <sub>PZL</sub> , t <sub>PZH</sub>	OE	r	C <sub>L</sub> = 15 pr	T <sub>A</sub> = -40°C to 85°C (SN74AHC125)			9.5	ns						
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)			9.5							
				T <sub>A</sub> = 25°C		7.0 <sup>(1)</sup>	9.7 <sup>(1)</sup>							
	O.F.	ŌĒ Y	C <sub>L</sub> = 15 pF	T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1(1)		11.5 <sup>(1)</sup>	ns						
t <sub>PLZ</sub> , t <sub>PHZ</sub>	OE	Y		T <sub>A</sub> = -40°C to 85°C (SN74AHC125)	1(1)		11.5 <sup>(1)</sup>							
										T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1(1)		11.5 <sup>(1)</sup>	
	А			T <sub>A</sub> = 25°C		8.1	11.5							
		А	Δ	Y	C <sub>1</sub> = 50 pF	T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1		13	ns				
t <sub>PHL</sub> , t <sub>PLH</sub>			Ţ	C <sub>L</sub> = 50 pF	$T_A = -40$ °C to 85°C (SN74AHC125)	1		13						
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		13							
										T <sub>A</sub> = 25°C		7.9	11.5	
	ŌĒ	Y	C <sub>L</sub> = 50 pF	T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1		13							
t <sub>PZL</sub> , t <sub>PZH</sub>	OE	Ţ	CL - 50 PF	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C (SN74AHC125)}$	1		13	ns						
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		13							
				T <sub>A</sub> = 25°C		9.5	13.2							
	ŌĒ		Y C <sub>L</sub> = 50 pF	T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1		15	ns						
t <sub>PLZ</sub> , t <sub>PHZ</sub>	UE	r		T <sub>A</sub> = -40°C to 85°C (SN74AHC125)	1		15							
			T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		15								
tck(a)	ŌĒ	Y	C <sub>1</sub> = 50 pF	T <sub>A</sub> = 25°C			1.5 <sup>(2)</sup>	no						
tsk(o)	OE.	i i	OL - 50 pr	T <sub>A</sub> = -40°C to 85°C (SN74AHC125)			1.5	ns						

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

<sup>(2)</sup> On products compliant to MIL-PRF-38535, this parameter does not apply.



## 6.7 Switching Characteristics, $V_{CC}$ = 5 V ± 0.5 V

over recommended operating free-air temperature range and  $V_{CC}$  = 5 V  $\pm$  0.5 V (unless otherwise noted; see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		TEST CONDITIONS	MIN	TYP	MAX	UNIT				
				T <sub>A</sub> = 25°C		3.8(1)	5.5 <sup>(1)</sup>					
				T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1 <sup>(1)</sup>		6.5 <sup>(1)</sup>					
t <sub>PLH</sub> , t <sub>PHL</sub>	Α	Α	Y	C <sub>L</sub> = 15 pF	$T_A = -40$ °C to 85°C (SN74AHC125)	1		6.5	ns			
				$T_A = -40$ °C to 125°C (recommended SN74AHC125)	1		6.5					
				T <sub>A</sub> = 25°C		3.6 <sup>(1)</sup>	5.1 <sup>(1)</sup>					
				$T_A = -55^{\circ}\text{C to } 125^{\circ}\text{C}$ (SN54AHC125)	1 <sup>(1)</sup>		6 <sup>(1)</sup>					
$t_{PZH}$ , $t_{PZL}$	ŌĒ	Y	C <sub>L</sub> = 15 pF	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$ (SN74AHC125)	1		6	ns				
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		6					
-				T <sub>A</sub> = 25°C		4.6 <sup>(1)</sup>	6.8 <sup>(1)</sup>					
				T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1 <sup>(1)</sup>		8 <sup>(1)</sup>					
$t_{PHZ}$ , $t_{PLZ}$	ŌĒ	ŌĒ	ŌĒ	ŌĒ	ŌĒ Y	Y	C <sub>L</sub> = 15 pF	$T_A = -40$ °C to 85°C (SN74AHC125)	1 <sup>(1)</sup>		8(1)	ns
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1 <sup>(1)</sup>		8(1)					
				T <sub>A</sub> = 25°C		5.3	7.5					
	A	А			$T_A = -55^{\circ}\text{C to } 125^{\circ}\text{C}$ (SN54AHC125)	1		8.5 8.5				
t <sub>PLH</sub> , t <sub>PHL</sub>			Y	C <sub>L</sub> = 50 pF	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$ (SN74AHC125)	1						
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		8.5					
				T <sub>A</sub> = 25°C		5.1	7.1					
			C <sub>L</sub> = 50 pF	T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1		8	ns				
t <sub>PZH</sub> , t <sub>PZL</sub>	ŌĒ	Y		$T_A = -40$ °C to 85°C (SN74AHC125)	1		8					
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		8					
				T <sub>A</sub> = 25°C		6.1	8.8					
				T <sub>A</sub> = -55°C to 125°C (SN54AHC125)	1		10	ns				
t <sub>PHZ</sub> , t <sub>PLZ</sub>	ŌĒ	Y	C <sub>L</sub> = 50 pF	$T_A = -40^{\circ}\text{C to } 85^{\circ}\text{C}$ (SN74AHC125)	1		10					
				T <sub>A</sub> = -40°C to 125°C (recommended SN74AHC125)	1		10					
			T <sub>A</sub> = 25°C			1(2)						
tsk(o)	ŌĒ	Y	C <sub>L</sub> = 50 pF	$T_A = -40$ °C to 85°C (SN74AHC125)			1	ns				



#### **6.8 Noise Characteristics**

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, \text{ and } T_A = 25^{\circ}\text{C}^{(1)}$ 

	PARAMETER	MIN	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic (V <sub>OL</sub> )		0.8	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic (V <sub>OL</sub> )		-0.8	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic (V <sub>OH</sub> )	4.4		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	3.5		V
$V_{IL(D)}$	Low-level dynamic input voltage		1.5	V

<sup>(1)</sup> Characteristics are for surface-mount packages only.

## **6.9 Operating Characteristics**

 $V_{CC}$  = 5 V and  $T_A$  = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
С	Power dissipation capacitance	No load and f = 1 MHz	9.5	pF

## **6.10 Typical Characteristics**

Figure 6-1 shows  $I_{CC}$  for varying  $V_{IN}$  values when  $V_{CC}$  is 5 V ±0.5 V and  $T_A$  = 25°C.

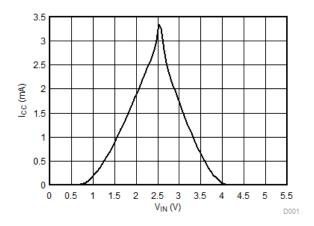
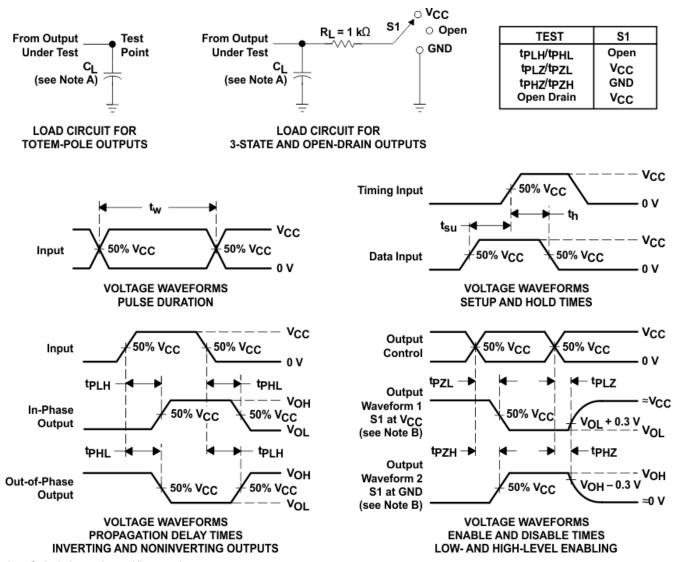


Figure 6-1. V<sub>IN</sub> vs I<sub>CC</sub>

### 7 Parameter Measurement Information



- C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_{\Omega}$  = 50  $\Omega$ ,  $t_r \leq$  3 ns,  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

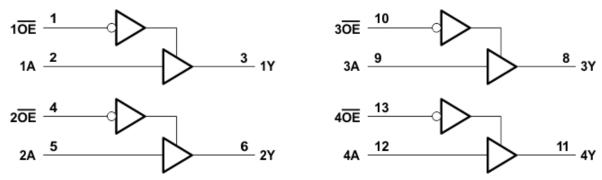
Figure 7-1. Load Circuit and Voltage Waveforms

## **8 Detailed Description**

## 8.1 Overview

The SNx4AHC125 devices have four integrated bus buffer gates. Each gate can be individually controlled from their respective output enable pins or tied together and controlled simultaneously. This allows for control of up to four different lines from one device. Often times a microcontroller have multiple function options for a single pin. By using GPIO pins to enable specific buffers, the SNx4AHC125 can act as a multiplexer to select a specific data line depending on what pin function is selected on the microcontroller. At the same time, the lines that are not selected are isolated from the pin.

### 8.2 Functional Block Diagram



Pin numbers shown are for the D, DB, DGV, J, N, NS, PW, RGY, and W packages.

### 8.3 Feature Description

Each buffer has its own output enable. This allows for control of each buffer individually. When the output enable is LOW, the input is passed to the output. When the output enable is HIGH, the output is high impedance. This feature is useful in applications that might require isolation.

#### 8.4 Device Functional Modes

Table 8-1 lists the functional modes of the SNx4AHC125.

Table 8-1. Function Table (Each Buffer)

INP	INPUTS					
ŌĒ	Α	Y				
L	Н	Н				
L	L	L				
Н	X	Z				



## 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 9.1 Application Information

The wide operating range of the SNx4AHC125 devices allows for implementation into a variety of applications. In addition to the wide operating range, these devices differentiate from similar devices because they have four buffers that can be individually controlled through their independent output enable ( $\overline{OE}$ ) pins. Each buffer is either enabled and passes data from A to Y, or disabled and set to a high-impedance state.

### 9.2 Typical Application

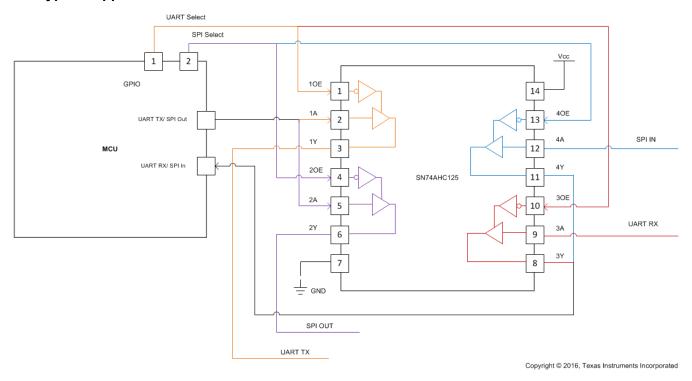


Figure 9-1. Digital MUX

#### 9.2.1 Design Requirements

It is best to set  $V_{CC}$  for the SN74AHC125 to the same level as the microcontroller logic levels. This allows for optimal performance. The SN74AHC125 can safely handle input levels from -0.5 V to 7 V. However, if the logic levels that are being received vary from the  $V_{CC}$  level of the device then errors can occur. For example, if  $V_{CC}$  is 5.5 V then the minimum high-level input voltage ( $V_{IH}$ ) level is 3.85 V. This means if the microcontroller is sending a HIGH signal, but HIGH = 3.3 V, it would be too low a level for the SNx4AHC125 to register it as what it must be. In this case  $V_{CC}$  would need to be lowered in order to lower the  $V_{IH}$  minimum. The opposite is also true for low-level input voltage ( $V_{IL}$ ). If VCC is set to 2 V, then  $V_{IL}$  maximum is 0.5 V. Depending on the microcontroller logic levels, a LOW signal may not go low enough for the SNx4AHC125 to register it.



## 9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
  - For V<sub>IH</sub> and V<sub>IL</sub> levels at varying V<sub>CC</sub>, see Recommended Operating Conditions.
  - Be mindful of rise time and fall time specifications for the output enable pins to ensure that the right buffers are enabled and the others are disabled in time. This minimizes interference on the microcontroller pin and to exterior circuitry. See *Switching Characteristics*,  $V_{CC} = 3.3 \ V \pm 0.3 \ V$  and *Switching Characteristics*,  $V_{CC} = 5 \ V \pm 0.5 \ V$  table for more details.
- 2. Recommended Output Conditions:
  - Load currents must not exceed I<sub>O</sub> maximum per output and must not exceed continuous current through V<sub>CC</sub> or GND total current for the part. These limits are located in the *Absolute Maximum Ratings*.
  - Outputs must not be pulled above V<sub>CC</sub>.

#### 9.2.3 Application Curves

Typical device at 25°C

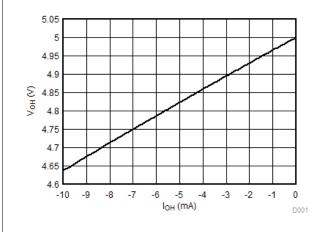


Figure 9-2. I<sub>OH</sub> vs V<sub>OH</sub>

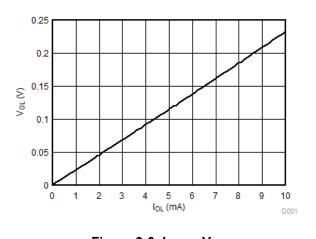


Figure 9-3.  $I_{OL}$  vs  $V_{OL}$ 



#### 9.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*.

Each  $V_{CC}$  pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- $\mu$ F capacitor is recommended and if there are multiple  $V_{CC}$  pins then a 0.01- $\mu$ F or 0.022- $\mu$ F capacitor is recommended for each power pin. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

#### 9.4 Layout

### 9.4.1 Layout Guidelines

When using multiple bit logic devices, inputs must not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, they are tied to GND or  $V_{CC}$  (whichever make more sense or is more convenient).

#### 9.4.1.1 Layout Example



Figure 9-4. Layout Diagram

## 10 Device and Documentation Support

## 10.1 Documentation Support (Analog)

## 10.1.1 Related Documentation

For related documentation see the following:

Implications of Slow or Floating CMOS Inputs (SCBA004)

#### 10.1.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 10-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHC125	Click here	Click here	Click here	Click here	Click here
SN74AHC125	Click here	Click here	Click here	Click here	Click here

### 10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 10.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

### 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



www.ti.com 27-Aug-2023

## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	<b>Device Marking</b> (4/5)	Samples
5962-9686801Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9686801Q2A SNJ54AHC 125FK	Samples
5962-9686801QCA	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QC A SNJ54AHC125J	Samples
5962-9686801QDA	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QD A SNJ54AHC125W	Samples
SN74AHC125BQAR	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125DGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC125N	Samples
SN74AHC125NE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC125N	Samples
SN74AHC125NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC125	Samples
SN74AHC125PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125PWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA125	Samples
SN74AHC125RGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HA125	Samples
SNJ54AHC125FK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9686801Q2A SNJ54AHC 125FK	Samples



www.ti.com 27-Aug-2023

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54AHC125J	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QC A SNJ54AHC125J	Samples
SNJ54AHC125W	ACTIVE	CFP	W	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9686801QD A SNJ54AHC125W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



www.ti.com 27-Aug-2023

#### OTHER QUALIFIED VERSIONS OF SN54AHC125, SN74AHC125:

● Catalog : SN74AHC125

• Automotive : SN74AHC125-Q1, SN74AHC125-Q1

● Enhanced Product: SN74AHC125-EP, SN74AHC125-EP

• Military : SN54AHC125

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications



www.ti.com 28-Aug-2023

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

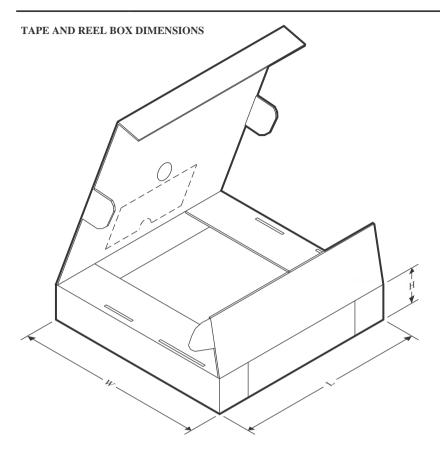


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC125BQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74AHC125DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHC125DGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AHC125DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC125NSR	so	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74AHC125PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC125RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



www.ti.com 28-Aug-2023



## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC125BQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74AHC125DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74AHC125DGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74AHC125DR	SOIC	D	14	2500	340.5	336.1	32.0
SN74AHC125NSR	SO	NS	14	2000	356.0	356.0	35.0
SN74AHC125PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHC125RGYR	VQFN	RGY	14	3000	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 28-Aug-2023

## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9686801Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9686801QDA	W	CFP	14	1	506.98	26.16	6220	NA
SN74AHC125N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC125N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC125NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC125NE4	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54AHC125FK	FK	LCCC	20	1	506.98	12.06	2030	NA
SNJ54AHC125W	W	CFP	14	1	506.98	26.16	6220	NA

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



## D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## DB (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

#### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



## RGY (S-PVQFN-N14)

## PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters



# RGY (S-PVQFN-N14)

## PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com

PLASTIC QUAD FLAT PACK-NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# W (R-GDFP-F14)

## CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



## DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated